

**3LN01M**

Ultrahigh-Speed Switching Applications

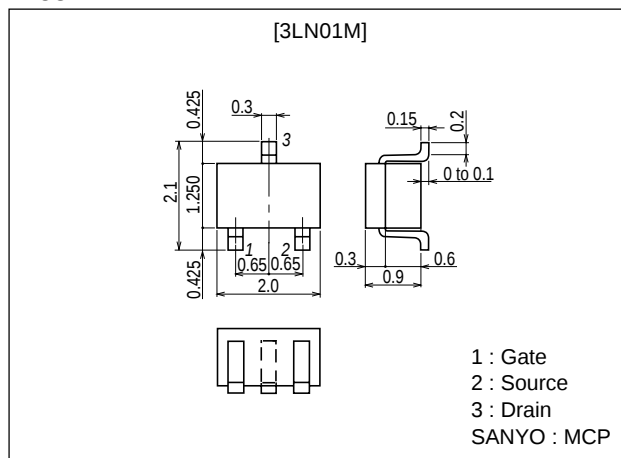
Features

- Low ON resistance.
- Ultrahigh-speed switching.
- 2.5V drive.

Package Dimensions

unit:mm

2158



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DS}		30	V
Gate-to-Source Voltage	V_{GS}		±10	V
Drain Current (DC)	I_D		0.15	A
Drain Current (pulse)	I_{DP}	PW≤10μs, duty cycle≤1%	0.6	A
Allowable Power Dissipation	P_D		0.15	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=1mA, V_{GS}=0$	30			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS}=30V, V_{GS}=0$			10	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS}=±8V, V_{DS}=0$			±10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS}=10V, I_D=100μA$	0.4		1.3	V
Forward Transfer Admittance	yfs	$V_{DS}=10V, I_D=80mA$	0.15	0.22		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)1}$	$I_D=80mA, V_{GS}=4V$		2.9	3.7	Ω
	$R_{DS(on)2}$	$I_D=40mA, V_{GS}=2.5V$		3.7	5.2	Ω
	$R_{DS(on)3}$	$I_D=10mA, V_{GS}=1.5V$		6.4	12.8	Ω

Marking : YA

Continued on next page.

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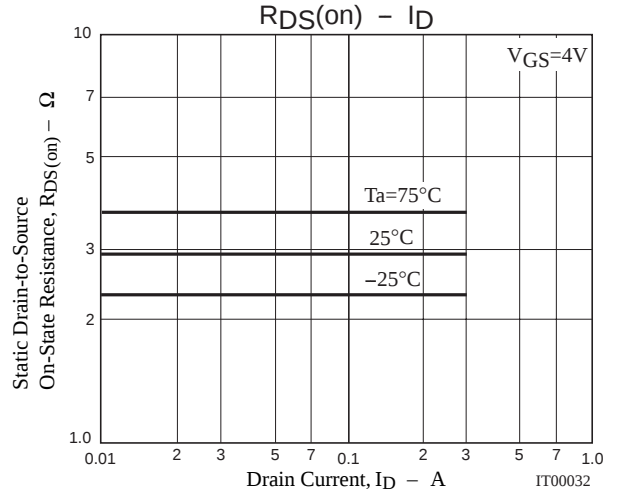
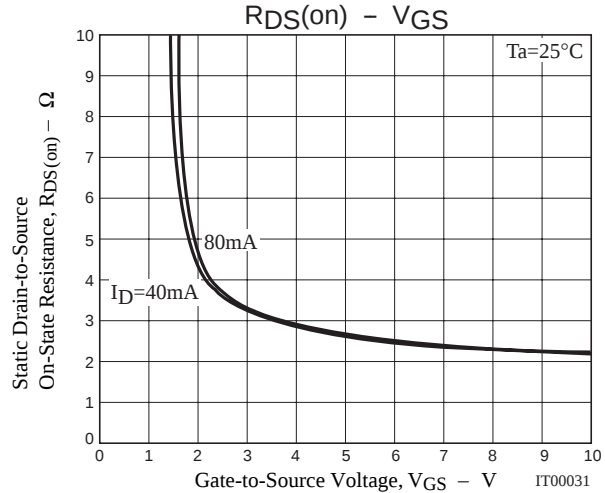
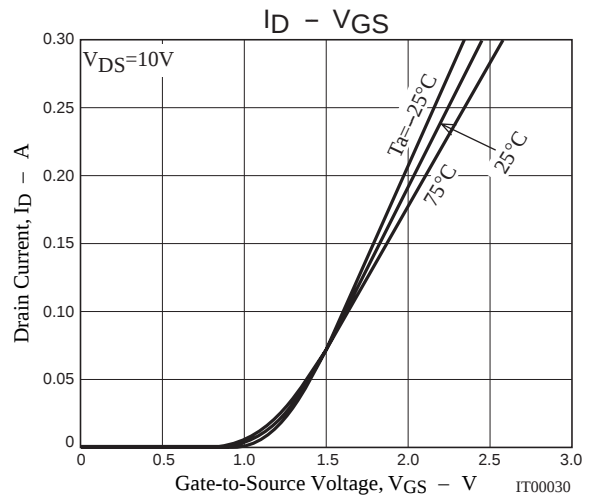
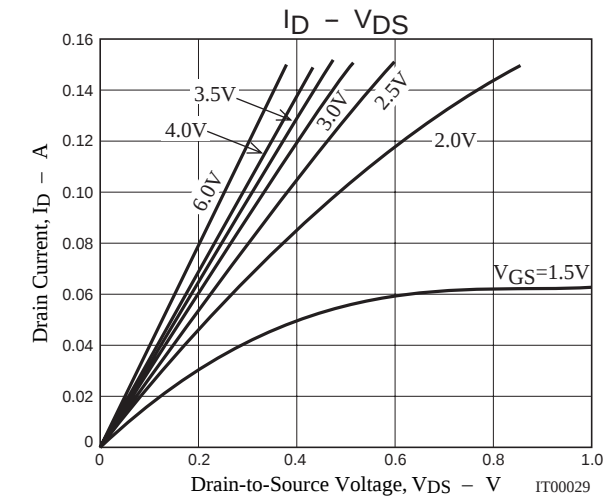
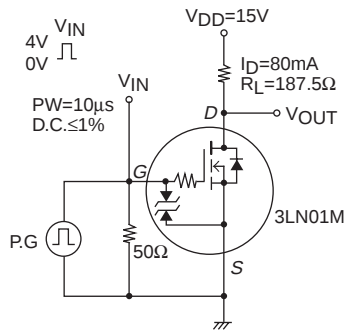
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3LN01M

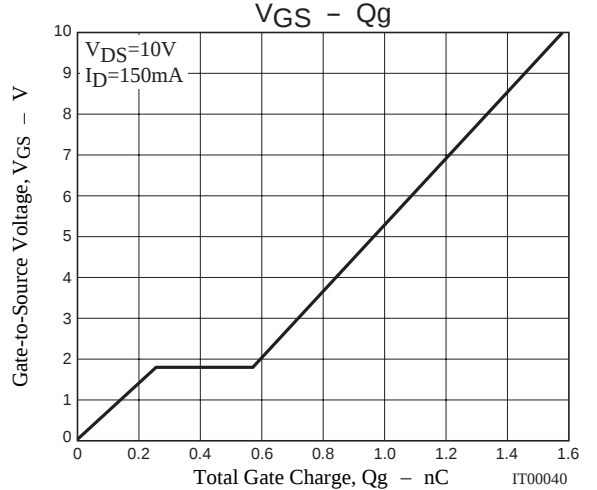
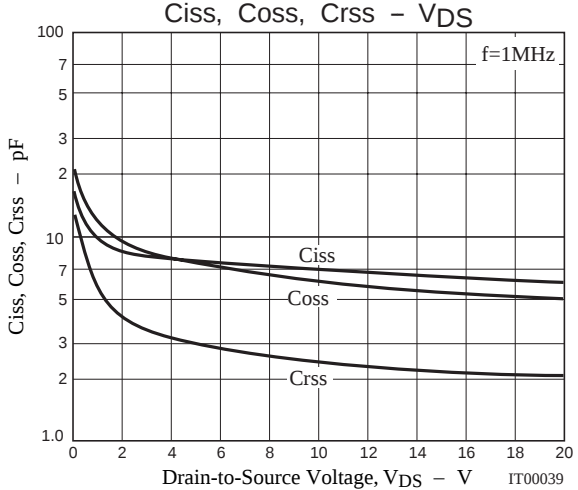
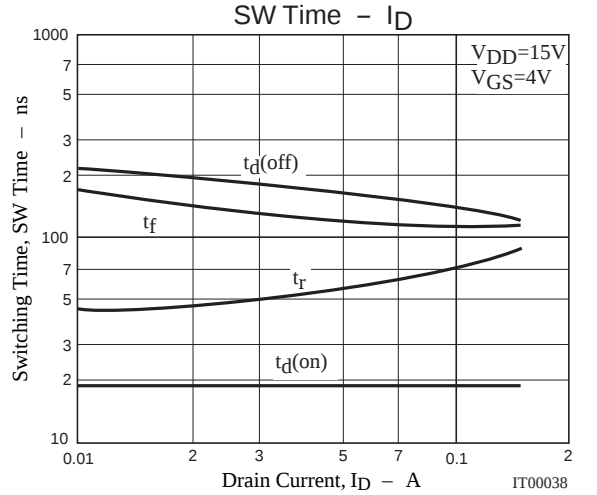
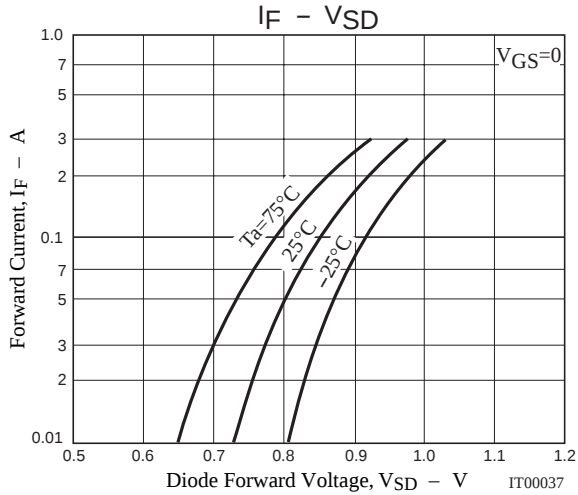
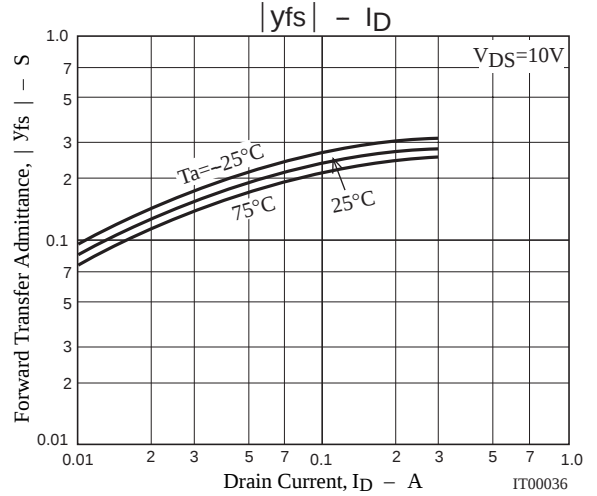
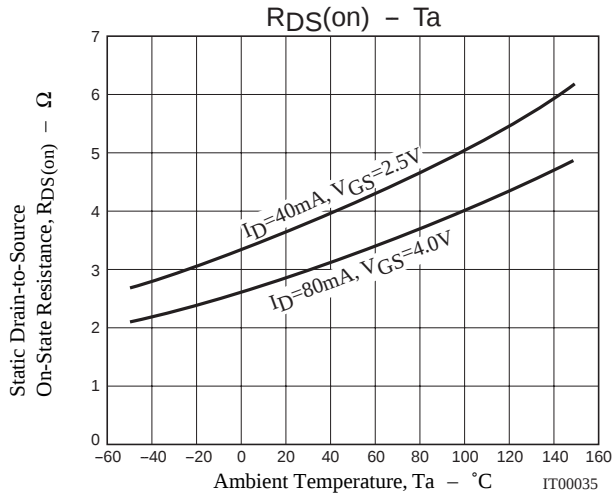
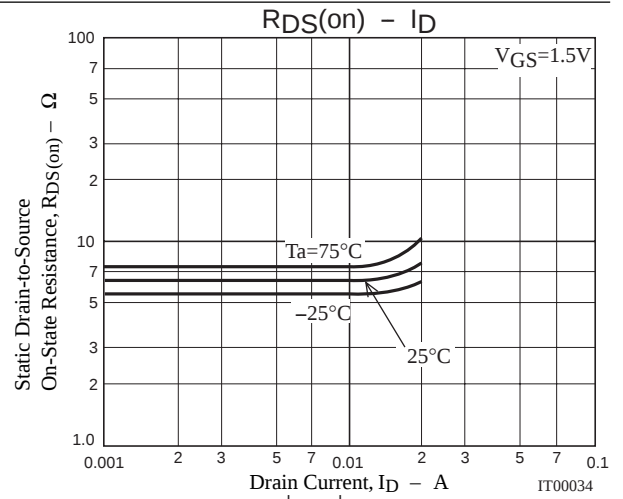
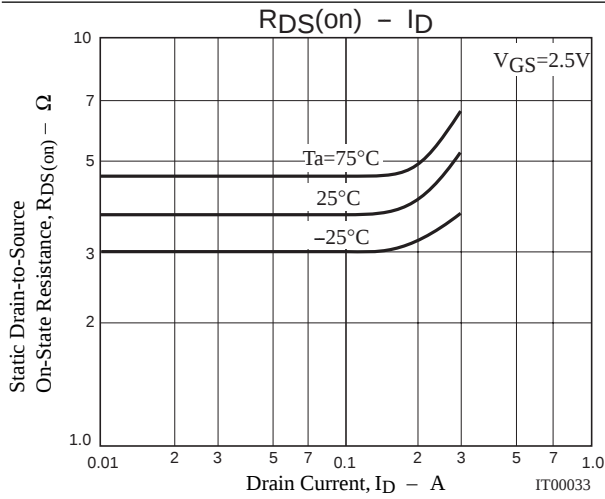
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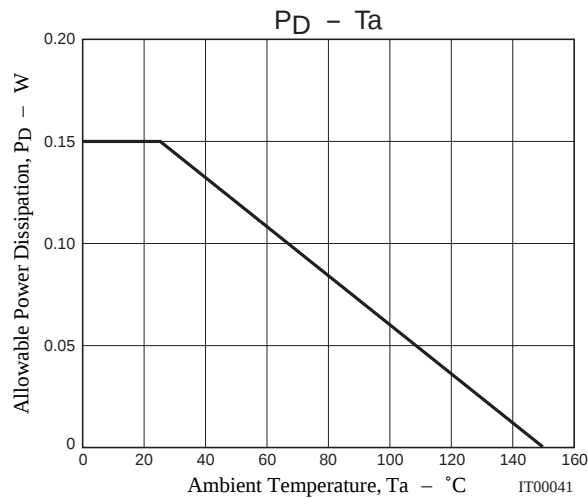
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Input Capacitance	Ciss	$V_{DS}=10V, f=1MHz$		7.0		pF
Output Capacitance	Coss	$V_{DS}=10V, f=1MHz$		5.9		pF
Reverse Transfer Capacitance	Crss	$V_{DS}=10V, f=1MHz$		2.3		pF
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit		19		ns
Rise Time	t_r	See specified Test Circuit		65		ns
Turn-OFF Delay Time	$t_{d(off)}$	See specified Test Circuit		155		ns
Fall Time	t_f	See specified Test Circuit		120		ns
Total Gate Charge	Qg	$V_{DS}=10V, V_{GS}=10V, I_D=150mA$		1.58		nC
Gate-to-Source Charge	Qgs	$V_{DS}=10V, V_{GS}=10V, I_D=150mA$		0.26		nC
Gate-to-Drain "Miller" Charge	Qgd	$V_{DS}=10V, V_{GS}=10V, I_D=150mA$		0.31		nC
Diode Forward Voltage	V_{SD}	$I_S=150mA, V_{GS}=0$		0.87	1.2	V

Switching Time Test Circuit



3LN01M





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